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1 <u>Supplementary Information</u>

2	Synthesis and Elucidation of Local Structure in Phase-Controlled Colloidal Tin Phosphide
3	Nanocrystals from Aminophosphines

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1 1. Characterization

2 **1.1 X-ray Diffraction (XRD)**

3 XRD characterization was performed using a Bruker AXS D8 DISCOVER GADDS
4 Microdiffractometer with Cu Kα radiation (λ = 0.154 nm). Samples were prepared by drop casting
5 a concentrated solution of nanoparticles from toluene onto a 1 cm x 1 cm <100> silicon substrate
6 inside of a nitrogen filled glovebox. XRD scans were collected using an incident angle of ω = 18°.
7 XRD data was processed using GSAS-II software.¹

8 1.1.2 Scherrer Analysis

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10 The crystal grain size, τ , is given by

11
$$\tau = \frac{K\lambda}{\beta cos\theta}$$

where *K* is the dimensionless Scherrer constant, λ is the X-ray wavelength in nm, β is the line broadening (FWHM) and θ is the Bragg angle in radians. In our analysis, K = 0.9 and $\lambda = 0.154$ nm. β was approximated from a Gaussian fit of diffraction peaks. The final crystal grain size was obtained by taking an average estimation from several peaks. For Sn₄P₃ nanocrystals, using the characteristic peak at $2\theta = 31^{\circ}$, a Gaussian fit provided $\beta = 0.514^{\circ}$, providing a $\tau = 20.2$ nm.

17 **1.2 Transmission Electron Microscopy (TEM)**

TEM samples were prepared on 300 mesh formvar/carbon grids (Ted Pella, FCF300-Cu-UA).
Bright field TEM images were obtained using a Tecnai Spirit 120kV TEM. The particle size distribution of each sample was determined using the ImageJ software.² For high resolution TEM (HRTEM), samples were prepared by drop casting a dilute filtered solution of nanoparticles dispersed in hexanes onto a TEM grid. Images were taken using a FEI Titan Themis 200 kV TEM.
Scanning transmission electron microscopy (STEM) images and energy dispersive X-ray (EDX)

measurements were acquired with a Hitachi HD2700C dedicated STEM with a probe Cs corrector
at an accelerating voltage of 200 kV.

3 **1.3 X-ray Photoelectron Spectroscopy (XPS)**

XPS data was measured using a Versa Probe II XPS from Physical Electronics with Al Kα source
operated at 50 W and 15 kV with an energy resolution of 700 meV and 200 µm spot size. Samples
were prepared by drop casting a solution of nanoparticles onto a 1 cm x 1 cm glass slide (Thin
Film Devices). The data was processed using MultiPak Data Reduction software, in which sample
spectra were calibrated to the carbon spectrum.

9 **1.4 X-ray Absorption Spectroscopy (XAS)**

X-ray absorption measurements were conducted at the 7-BM (Quick Absorption and Scattering, 10 11 QAS) beamline at NSLS-II. Samples were prepared by drop casting dispersions of nanoparticles from toluene, and drying them to make thick films onto pieces of Kapton. The Kapton pieces were 12 then folded and sealed with Kapton tape under an inert nitrogen atmosphere prior to sample 13 loading. Extended X-ray absorption fine structure (EXAFS) measurements at the Sn K-edge were 14 performed in transmission mode using a Si (111) crystal monochromator detuned by 20%. Sn foil 15 16 was used for calibration and alignment of all data in X-ray energy. The ionization chambers were filled with 90% Ar and 10% N₂. 17

EXAFS data was processed using the Demeter software package (Athena and Artemis).³ The collected XAS spectra were aligned, merged, normalized, and background subtracted in Athena. The theoretical EXAFS spectra were then constructed using the FEFF6 code incorporated in Artemis. The fitting was performed in r-space using a Hanning window applied to the k²- weighted data. The amplitude reduction factor (S₀²) was obtained from fitting EXAFS data for the Sn foil collected at QAS fitted to Sn metal (ICSD-236667) and was determined to be 1.1 ± 0.2 . Corrections

- 1 to the theoretical photoelectron energy (ΔE_0), the nearest coordination number (N), and the
- 2 disorder term (σ^2) were varied during the fits.

2. Supplementary Figures and Tables

- **Table S1.** Legend of Phases and Figures

Phase	Corresponding Figures
SnP	Figure 3, Figure 6, Figure 7, Figure 8a, Figure 8b
Sn ₄ P ₃	Figure 4, Figure, Figure 7, Figure 8c, Figure 8d
Sn_3P_4	Figure 5, Figure 6, Figure 7, Figure 8e, Figure 8d, Figure S7

- **Table S2.** List of the structure models used in the EXAFS fitting approach.

Model	Identifier	Structure and Space Group	Coordination Environment (Number)	Radial Distance (Å)
SnP	ICSD-16077	Tetragonal I 4 m m	Sn-P (3)	2.63
SnP	ICSD-69026	Trigonal P -3 m 1	Sn-P (2) Sn-P (1)	1.96 2.52
Sn3P4	Huang <i>et al.</i> ⁴	Trigonal P 3 1 c	Sn-P (1) Sn-P (3)	2.48 2.52
Sn3P4	COD-4001104	Hexagonal R -3 m	Sn-P (12)	2.68
Sn4P3	ICSD-15014	Rhombohedral R -3 m H	Sn-P (3)	2.66
SnO	ICSD-16481	Tetragonal P 4 / n m m	Sn-O (1)	1.84



Figure S1. The effect of the ratio of zinc to tin on reaction products. X-ray diffraction data (XRD)
for nanoparticles synthesized in the absence of ZnCl₂, a 1:4 ratio, a 1:1 ratio, and a 5:1 ratio of
ZnCl₂:SnCl₂, are shown. All other reaction parameters were held constant across syntheses. Data
are plotted against reference data for SnP (ICSD-69026), Sn₄P₃ (ICSD-15014), and Sn₃P₄ (Huang
et al.⁴). At all ratios, we obtained phase-mixtures of various tin phosphides.



Figure S2. The effect of the amount of oleylamine (OLA) on reaction products. X-ray diffraction
data (XRD) for nanoparticles synthesized in a 7.5:1, 15:1, and 30:1 ratio of OLA to
trisdiethylaminophosphine (PNEt₂)₃, are shown. All other reaction parameters were held constant
aross experiments. The data is plotted against reference data for SnP (JCPDS-69026) and Sn₄P₃
(ICSD-15014). Increasing the ratio of oleylamine to P(NEt₂)₃ drove the reaction pathway towards
SnP. At the highest ratio of oleylamine to P(NEt₂)₃, we obtained a phase pure SnP.



Figure S3. Phase data for tin phosphide nanocrystals grown under one-pot (solid) and two-pot
 (dashed) conditions. The data showed a similar trend regardless of method; increasing the ratio of
 oleylamine (OLA) to trisdiethylaminophosphine ((PNEt₂)₃) shifted the reaction towards phase pure SnP nanocrystals.



- 2 **Figure S4**. Dispersion of nanoparticles in toluene after filtration through 0.2 μm PTFE membrane
- 3 from (a) synthesis without oleic acid, in which case particles aggregated and did not filter, and (b)
- 4 synthesis with oleic acid, in which particles filtered.



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Figure S5. X-ray diffraction (XRD) data for tin phosphide nanocrystals grown in the presence of varying amounts of trioctylamine (TOA) (15 mL, 20 mL,) for 2 minutes at 250°C following

- injection of trisdiethylaminophosphine. (P(NEt₂)₃) for 2 minutes at 250 °C. Data is plotted against
- 9 reference data for Sn_4P_3 (ICSD-15014), SnP (ICSD-69026), and Sn_3P_4 (Huang *et al.*⁴).



Figure S6. The effect of temperature on reaction products. X-ray diffraction (XRD) data for tin
phosphide nanocrystals grown for 2 min at 250 °C following injection of
trisdiethylaminophosphine (PNEt₂)₃ into 20 mL of oleylamine and equimolar amounts of SnCl₂
and ZnCl₂ at 180 °C and 220 °C. The data were comparable to a trigonal Sn₃P₄ structure predicted
by Huang *et al.*



- 2 Figure S7. Phase and morphology of Sn_3P_4 nanocrystals. (a) X-ray diffraction data (XRD)
- 3 obtained for Sn_3P_4 nanocrystals plotted against reference data for trigonal Sn_3P_4 provided by
- Huang *et al.*⁴ (b) Bright field TEM images for synthesized nanocrystals. (c) Scanning transmission
 electron microscopy (STEM) images and energy dispersive X-ray (EDX) data for synthesized
- 6 nanocrystals.



Figure S8. Survey data obtained for SnP measured using x-ray photoelectron spectroscopy (XPS).



Figure S9. Survey data obtained for Sn_3P_4 measured using x-ray photoelectron spectroscopy (XPS).



Figure S10. Survey data obtained for Sn₄P₃ measured using x-ray photoelectron spectroscopy
 (XPS).

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Table S2. Best fit parameters obtained by EXAFS analysis of the k²-weighted spectrum of the synthesized SnP. The experimental data was fit against trigonal SnP (ICSD-69026). R-factor as well as reduced χ_{red}^2 are included. SnP data were fit with an *r* range of 1.1 to 2.8 Å and *k* range of 2.0 to 9.0 Å⁻¹. Sn-O and Sn-P photoelectron paths were used in the fits.

Structure Model	ucture IodelPathN $R(Å)$ $\sigma^2(Å^2)$		$\sigma^2(\text{\AA}^2)$	ΔE0 (eV)	R(%)	χred ²	S_0^2
SnP	Sn-O	0.7±0.4	2.02±0.18	0.0057±0.0068	75105	0.4 11	1 1
69026)	Sn-P	2.9±0.7	2.69 ± 0.13	0.012±0.0034	1.5±0.5		11

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- Table S3. Influence of k weighting on the obtained coordination numbers N by EXAFS analysis
- of synthesized SnP. The experimental data was fit against trigonal SnP (ICSD-69026). SnP data were fit with an *r* range of 1.1 to 2.8 Å and k range of 2.0 to 9.0 Å⁻¹. Sn-O and Sn-P photoelectron
- paths were used in the fits.

Path	Ν	k weighting
Sn-O	0.7±0.5	ŀ
Sn-P	2.6±0.8	K
Sn-O	0.7±0.4	\mathbf{k}^2
Sn-P	2.9±0.7	K
Sn-O	1.0±0.6	k3
Sn-P	2.7±0.6	K
Sn-O	0.7±0.4	k k ²
Sn-P	2.6±0.7	к, к
Sn-O	0.8±0.4	$k^2 k^3$
Sn-P	2.7±0.6	к , к
Sn-O	0.7±0.4	$k k^2 k^3$
Sn-P	2.6±0.7	к, к , к

Table S4. Best fit parameters obtained by EXAFS analysis of the k^2 -weighted spectrum of the

synthesized Sn₄P₃. The fit was performed using an Sn-P path for the rhombohedral phase of Sn₄P₃ (ICSD-15014). The fits were performed using a k range of 2.3 to 11.45 Å⁻¹ and an r range of 1.45

to 3 Å.

Structure	Path	Ν	R(Å)	σ^2 (Å ²)	ΔE ₀ (eV)	R	S 0 ²	χ red ²
Model						(%)		
Sn ₄ P ₃	Sn-P	1.2±0.1	2.65 ± 0.02	0.0085 ± 0.0013	6.3±0.9	1.3	1.1	64
(ICSD-								
15014)								

Table S5. Best fit parameters obtained by EXAFS analysis of the k^2 -weighted spectrum of the

synthesized Sn₃P₄. The fit was performed using the Sn-P path for tetragonal phase of SnP (ICSD-

16077). R-factor as well as reduced χ^2 are included. The fits were performed using a k range of 2.5

to 10.5 Å⁻¹ and an r range of 1.1 to 2.7 Å.

Structure Model	Path	N	R(Å)	σ^2 (Å ²)	ΔE0 (eV)	R(%)	S ₀ ²	χred ²
Sn ₃ P ₄	Sn-O	0.3±0.3	2.03±0. 19	0.0040 ± 0.0084	8.2±1.4	1.5	1.1	12
(ICSD- 16077)	Sn-P	1.3±0.2	2.66±0. 18	0.0054 ± 0.0014				15

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